

STM6502, STM6503 STM6504, STM6505

Dual push-button Smart ResetTM with user-adjustable setup delays

Features

- Dual Smart Reset push-button inputs with extended reset setup delay
- Adjustable Smart Reset setup delay (t_{SRC}): by external capacitor or three-state logic (product options): t_{SRC} = 2, 6, 10 s (min.)
- Power-on reset
- Single RST output, active-low, open-drain
- Factory-programmable thresholds to monitor V_{CC} in the range of 1.575 to 4.625 V typ.
- Operating voltage 1.0 V (active-low output valid) to 5.5 V
- Low supply current
- Operating temperature: industrial grade –40 °C to +85 °C
- TDFN8 package: 2 mm x 2 mm x 0.75 mm
- RoHS compliant



Applications

- Mobile phones, smartphones
- e-books
- MP3 players
- Games
- Portable navigation devices
- Any application that requires delayed reset push-button(s) response for improved system stability

			,							
Part number	Voltage inputs		Smart Reset inputs		t _{SRC} programming		Reset or Power Good outputs			
	v _{cc}	V _{BAT}	SR0	SR1	SRE immediate, independent	Ext. SRC pin	Three- state input TSR	RST	BLD	Package
STM6502 ⁽¹⁾	1		1	1		1		1		TDFN-8L
STM6503	1		1	1			1	1		TDFN-8L
STM6504 ⁽¹⁾	1		1		1		1	1		TDFN-8L
STM6505	1	1	~	1		1		1	1	TDFN-8L

Table 1.Device summary

1. Contact local ST sales office for availability.

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1 Description

STM6502 has two combined Smart Reset inputs ($\overline{SR0}$ and $\overline{SR1}$) with delayed Smart Reset setup time (t_{SRC}) programmed by an external capacitor on the SRC pin.

STM6503 is similar to STM6502, has two combined delayed Smart Reset inputs (SR0, SR1) and three user-selectable delayed Smart Reset setup time (t_{SRC}) options of 2 s, 6 s and 10 s through a three-state TSR input pin: when connected to ground, $t_{SRC} = 2$ s; when left open, $t_{SRC} = 6$ s; when connected to V_{CC}, $t_{SRC} = 10$ s (all the times are minimum).

STM6504 has two independent Smart Reset inputs. SR0 provides the delayed Smart Reset setup time (t_{SRC}) function with three user-selectable t_{SRC} options through a three-state TSR input pin: when connected to ground, $t_{SRC} = 2$ s; when left open, $t_{SRC} = 6$ s; when connected to V_{CC} , $t_{SRC} = 10$ s (all the times are minimum). SRE provides instant reset. SRE is edge-triggered with a special debounce time ($t_{DEBOUNCE} = 240$ ms min.) at the falling edge after a valid reset period.

STM6505 has two combined delayed Smart Reset inputs (SR0, SR1) and provides an adjustable reset delay setup time via an external capacitor connected to the SRC pin. The RST output depends also on the V_{CC} monitoring threshold. STM6505 also provides independent low battery detect (BLD) output controlled by the secondary external input voltage V_{BAT}. V_{BAT} is monitored for low voltage and provides an indication on the battery low detect output pin (BLD). V_{BAT} threshold is 1.25 V, fixed, and an external resistor divider is to be used to set the actual battery voltage threshold. V_{BAT} threshold hysteresis is 8 mV typ. (16 mV max.). V_{BAT} is voltage monitoring input only, the device is powered only from the V_{CC} pin; V_{CC} must be \geq 1.575 V for proper operation of the V_{BAT} comparator.

1.1 Smart Reset devices

The Smart Reset device family STM65xx provides a useful feature that ensures inadvertent short reset push-button closures do not cause system resets. This is done by implementing extended Smart Reset input delay (t_{SRC}). Once the valid Smart Reset input levels and setup delay are met, the device generates an output reset pulse with user-programmable timeout period (t_{REC}).

The Smart Reset inputs can be also connected to the applications interrupt to allow the control of both the interrupt pin and the hard reset functions. If the push-buttons are closed for a short time, the processor is only interrupted. If the system still does not respond properly, holding the push-buttons for the extended setup time (t_{SRC}) causes hard reset of the processor through the reset outputs. The Smart Reset feature helps significantly increase system stability.

The STM65xx family of Smart Reset devices consists of low current microprocessor reset circuits targeted at applications such as MP3 players, navigation, smartphones or mobile phones; generally any application that requires delayed reset push-button(s) response for improved system stability. The STM65xx devices feature single or dual Smart Reset inputs (SR). The delayed Smart Reset setup time (t_{SRC}) options of 2 s, 6 s and 10 s (all min.) are adjustable by an external capacitor on the SRC pin or selectable by three-state logic. The delayed setup period ignores switch closures shorter than t_{SRC} , thus preventing unwanted resets.



The STM65xx devices have active-low (optionally active-high) open-drain reset (RST) output(s) with or without internal pull-up resistor or push-pull as output options, with factory-programmed or capacitor-adjustable or push-buttons defined output reset pulse duration, with or without power-on reset function.

Some devices also have an undervoltage monitoring feature: the reset output is also asserted when the monitored supply voltage V_{CC} drops below the specified threshold. The reset output remains asserted for the reset timeout period (t_{REC}) after the monitored supply voltage goes above the specified threshold.





Figure 2. Pin connections

RST [1 O VSS [2 STM SR1 [3 6502 NC [4	 8 VCC 7 SR0 6 SRC 5 NC 	RST 1 0 8 V _{CC} VSS 2 STM 7 SR0 SR1 3 6503 6 TSR NC 4 5 NC
RST [1 O VSS [2 STM SRE [3 ⁶⁵⁰⁴ NC [4	8] V _{CC} 7] SR0 6] TSR 5] NC	RST 1 0 8 V _{CC} VSS 2 STM 7 SR0 SR1 3 6505 6 SRC BLD 4 5 V _{BAT} AM00379



Table 2.	Signal halles				
Symbol	Input/ output	Description			
RST	Output	Open-drain reset output, active-low.			
BLD	Output	Battery low detect output, active-low, open-drain. STM6505 only.			
SR0	Input	Primary push-button Smart Reset input. Active-low, with or without internal 65 k Ω pull-up to V _{CC} (product options).			
SR1	Input	Secondary push-button Smart Reset input - combines with the primary push- button reset to provide setup delay time before reset. Active-low, with or without internal 65 k Ω pull-up to V _{CC} (product options).			
SRE	Input	Secondary push-button Smart Reset input - provides instant Smart Reset. SRE is edge-triggered with a special debounce time ($t_{DEBOUNCE}$ = 240 ms min.) at the falling edge after a valid reset period. Active-high, no internal pull-up to V _{CC} . STM6504 only.			
SRC	Input	Smart Reset input delay setup control: connect to an external capacitor to adjust the delay setup time (t_{SRC}). STM6502 and STM6505 only.			
TSR	Input	A three-state Smart Reset input delay setup control. When connected to ground, $t_{SRC} = 2$ s; when left open, $t_{SRC} = 6$ s; when connected to V_{CC} , $t_{SRC} = 10$ s (all times are minimum). TSR is a DC-type input, intended to be either permanently grounded, permanently connected to V_{CC} or permanently left open. If left open, for improved system glitch immunity it is strongly recommended to connect a 0.1 μ F decoupling ceramic capacitor between the TSR and V_{SS} pins. STM6503 and STM6504 only.			
v _{cc}	Supply	Supply voltage input. Power supply for the device and an input for the monitored supply voltage. A 0.1 μF decoupling ceramic capacitor is recommended to be connected between the V _{CC} and V _{SS} pins.			
V _{BAT}	Input	Battery voltage monitoring input. STM6505 only.			
V _{SS}	Supply	Ground			
NC		No connect (not bonded); should be connected to V _{SS} .			

Table 2.Signal names





Figure 3. Block diagram - STM6502, STM6503, STM6504

 STM6504 only: SR0 and SRE are working independently. SRE is edge-triggered and has a special debounce time (t_{DEBOUNCE} = 240 ms min.) at the falling edge after a valid reset period.



Figure 4. Block diagram - STM6505



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Figure 5. Single-button Smart Reset typical hookup





1.2 Pin descriptions

1.2.1 Power supply (V_{CC})

This pin is used to provide the power to the device and to monitor the power supply. A 0.1 μF decoupling ceramic capacitor is recommended to be connected between the V_{CC} and V_{SS} pins.

1.2.2 Ground (V_{SS})

This is the supply ground for the device.

1.2.3 Primary Smart Reset input (SR0)

The primary push-button Smart Reset input, active-low pin is connected to the first pushbutton switch.

1.2.4 Secondary Smart Reset input (SR1)

The secondary push-button Smart Reset input, active-low pin is connected to the second push-button switch. Keeping both Smart Reset inputs $\overline{SR0}$ and $\overline{SR1}$ active for longer than t_{SRC} activates the reset output pulse.

Figure 7. STM6502, STM6503 timing



Reset is asserted "low" right after the Smart Reset setup delay (t_{SRC}) has been met and returns to high after the t_{REC} period.



1.2.5 Edge-triggered Smart Reset input (SRE pin) – STM6504 only

The SRE pin is active-high, immediate and independent reset input that includes an edge trigger with debounce delay t_{DEBOUNCE} on the falling edge.







1.2.6 Adjustable delay of Smart Reset input (SRC pin) – STM6502 and STM6505 only

This pin controls the setup time before the push-button action is validated by the reset output. It is connected to an external capacitor (C_{SRC}), which is tied to ground to provide the desired value of the setup time (t_{SRC}).

Calculated t_{SRC} and C_{SRC} examples are given in *Table 3*. Refer also to *Table 6*.

Calculated C _{SRC}	Se	Closest common		
value [µF]	Min.	Тур.	Max.	C _{SRC} value [µF]
0.2	2	2.5	3.0	0.22
0.3	3	3.75	4.5	0.33
0.6	6	7.5	9	0.56
1	10	12.5	15	1

Table 3.	t _{SRC} programmed by an ideal external capacitor – STM6502 and STM6505
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1. At 25 °C. Example calculations based on an ideal capacitor. During application design and component selection it should be considered that the current flowing into the external t_{SRC} programming capacitor (C_{SRC}) is on the order of 100 nA, therefore a low-leakage capacitor (ceramic or film capacitor) should be used and placed as close as possible to the SRC pin. Also an adequate low-leakage PCB environment should be ensured to prevent t_{SRC} accuracy from being affected. A recommended minimum value of C_{SRC} is 0.01 µF.

2. In case of repeated activations of the t_{SRC} timer, an interval of 10 ms min. is needed between the activations to fully discharge C_{SRC} , so that the next t_{SRC} is as specified.



1.2.7 Programmable Smart Reset input delay (TSR pin) – STM6503 and STM6504 only

The TSR pin allows the user to program the setup time before the push-button action is validated by the reset output. It is controlled by different voltage levels on the three-state TSR input pin: when connected to ground, $t_{SRC} = 2$ s; when left open, $t_{SRC} = 6$ s; when connected to V_{CC} , $t_{SRC} = 10$ s (all times are minimum). TSR is a DC-type input, intended to be either permanently grounded, permanently connected to V_{CC} or permanently left open. If it is left open, for improved system glitch immunity it is strongly recommended to connect a 0.1 µF decoupling ceramic capacitor between the TSR and V_{SS} pins.

1.2.8 Reset output (RST)

RST is the active-low, open-drain reset output in the Smart Reset family.

1.2.9 Battery monitoring input (V_{BAT}) – STM6505 only

 V_{BAT} is an input for monitoring the battery voltage. V_{BAT} threshold is 1.25 V, fixed, and an external resistor divider is to be used to set the actual battery voltage threshold.

1.2.10 Battery low detect output (BLD) – STM6505 only

The battery low detect output is controlled by the V_{BAT} voltage monitoring input and is active-low, open-drain, with no pull-up.







2 Typical operating characteristics





Figure 11. Smart Reset delay (t_{SRC}) vs. temperature, $C_{SRC} = 0.62 \ \mu F$ (STM6505)







Figure 12. Reset threshold (V_{RST}) vs. temperature, "S" threshold option, V_{CC} falling (STM6505)







3 Maximum ratings

Stressing the device above the rating listed in *Table 4: Absolute maximum ratings* may cause permanent damage to the device. These are stress ratings only and operation of the device at these or any other conditions above those indicated in the operating sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability. Refer also to the STMicroelectronics SURE Program and other relevant quality documents.

Symbol	Parameter	Value	Unit	
T _{STG}	Storage temperature (V _{CC} off)		-55 to +150	°C
T _{SLD} ⁽¹⁾	Lead solder temperature for 10 seconds		260	°C
θ_{JA}	Thermal resistance (junction to ambient) TDFN8		149.0	°C/W
V _{IO}	Input or output voltage		-0.3 to 5.5 ⁽²⁾	V
V _{CC}	Supply voltage		–0.3 to 7	V

Table 4. Absolute maximum ratings

1. Reflow at peak temperature of 260 °C. The time above 255 °C must not exceed 30 seconds.

2. For inputs or outputs with internal pull-up resistors and push-pull type outputs –0.3 to V_{CC} +0.3 V only.



4 DC and AC parameters

This section summarizes the operating measurement conditions, and the DC and AC characteristics of the device. The parameters in the DC and AC characteristics tables that follow, are derived from tests performed under the measurement conditions summarized in *Table 5: Operating and measurement conditions*. Designers should check that the operating conditions in their circuit match the operating conditions when relying on the quoted parameters.

Parameter	Value	Unit
V _{CC} supply voltage	1.0 to 5.5	V
Ambient operating temperature (T _A)	-40 to +85	°C
Input rise and fall times	≤ 5	ns
Input pulse voltages	0.2 to 0.8 V _{CC}	V
Input and output timing ref. voltages	0.3 to 0.7 V _{CC}	V

Table 5. Operating and measurement conditions

Figure 14. AC testing input/output waveforms





Symbol	Parameter		Test conditions ⁽¹⁾	Min.	Тур. ⁽²⁾	Max.	Unit
V _{CC}	Supply voltage range	Reset outp	Reset output valid - active-low			5.5	V
		STM6502			1.2		μA
		51100502	$V_{CC} = 3.0 V^{(3)}$		1.1		μA
		STM6503	V _{CC} = 5.0 V, TSR left open		4	5.8	μA
1	Supply current (inputs in	31100003	V_{CC} = 3.0 V, TSR left open ⁽³⁾		3		μA
Icc	their inactive state)	STM6504	V _{CC} = 5.0 V, TSR left open		4	5.8	μA
		31100304	V_{CC} = 3.0 V, TSR left open ⁽³⁾		3		μA
		STM6505	V _{CC} = 5.0 V		2.3	3.3	μA
		31100000	$V_{\rm CC} = 3.0 \ V^{(3)}$		2.2		μA
Output cha	aracteristics						
V _{OL}		$V_{CC} \ge 4.5$ V, sinking 3.2 mA				0.3	V
	Reset output voltage low (reset asserted: RST, BLD)	$V_{CC} \geq 3.3$ V, sinking 2.5 mA				0.3	V
	,	$V_{CC} \ge 1.0$ V, sinking 0.1 mA				0.3	V
+	Reset timeout delay,	Option A		140	210	280	ms
t _{REC}	factory-programmed	Option B		240	360	480	ms
V _{CC} monit	oring reset thresholds						
V	Fixed voltage trip point for	–40 to +85 °C		V _{RST} –2.5%	V _{RST}	V _{RST} +2.5%	v
V _{RST}	V _{CC} monitoring (refer to <i>Table 7</i>)	25 °C		V _{RST} -2.0%	V _{RST}	V _{RST} +2.0%	v
M		L, M			0.5%		
V _{HYST}	Hysteresis of V _{RST}	T, S, R, Z, Y, W, V			1%		
	V _{CC} to reset delay	V_{CC} falling from (V_{RST} + 100 mV) to (V_{RST} - 100 mV) at 10 mV/ $\mu s^{(4)}$			20		μs
V _{BAT} moni	toring						
V _{BATTH}	Fixed V _{BAT} monitoring threshold	STM6505	only	1.225	1.25	1.275	v
V _{BATHYST}	V _{BATTH} hysteresis	STM6505		8	16	mV	
I _{LI(VBAT)}	V _{BAT} input leakage current	STM6505	only	-100	10	100	nA

Table 6.DC and AC characteristics



Symbol	Parameter	Test conditions ⁽¹⁾	Min.	Тур. ⁽²⁾	Max.	Unit
Smart Res	et inputs		1			<u></u>
V _{IL}	SR0, SR1, SRE input voltage low		V _{SS} -0.3		0.3 V _{CC}	v
V _{IH}	SR0, SR1, SRE input voltage high		0.7 V _{CC}		5.5	v
I _{LI(SR)}	Input leakage current, \overline{SR} and SRE inputs	Option without internal pull-up resistor	-1		+1	μA
I _{LI(TSR)}	Input leakage current, TSR input	STM6503 and STM6504 only	-5		+7	μA
R _{PUI}	Internal pull-up resistor, input (optional - refer to <i>Table 12</i>)			65		kΩ
t _{DEBOUNCE}	SRE input falling edge debounce time	STM6504 only	240	360	480	ms
Smart Res	et delay					
t _{SRC} ⁽⁵⁾	Capacitor-programmable Smart Reset setup time, STM6502 and STM6505. Refer to <i>Table 3</i> .	T _A = 25 °C	10 x C _{SRC} (µF)	12.5 x C _{SRC} (µF)	15 x C _{SRC} (μF)	S
	TSR pin-programmable	TSR = V _{SS}	2	2.5	3	s
t _{SRC} ⁽⁵⁾	Smart Reset setup time,	TSR = floating ⁽⁶⁾	6	7.5	9	s
	STM6503 and STM6504.	TSR = V _{CC}	10	12.5	15	s

Table 6.	DC and AC c	haracteristics (continued)
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1. Valid for ambient operating temperature: $T_A = -40$ to +85 °C; $V_{CC} = 1.0$ to 5.5 V (except where noted).

2. Typical value is at 25 $^\circ\text{C}$ and V_{CC} = 3.3 V unless otherwise noted.

3. For devices with $V_{RST} < 3.0 V$.

4. Guaranteed by design.

5. Input glitch immunity is equal to t_{SRC} (when both SR inputs are low, otherwise infinite). STM6502, STM6503, STM6505 only.

If left open, for improved system glitch immunity it is strongly recommended to connect a 0.1 µF decoupling ceramic capacitor between the TSR and V_{SS} pins.





V _{CC} monitoring threshold	Ture	±2.5% (–40 °	°C to +85 °C)	±2.0%	11	
V _{RST}	Тур.	Min.	Max.	Min.	Max.	- Unit
L (falling)	4.625	4.509	4.741	4.533	4.718	V
M (falling)	4.375	4.266	4.484	4.288	4.463	V
T (falling)	3.075	2.998	3.152	3.014	3.137	V
S (falling)	2.925	2.852	2.998	2.867	2.984	V
R (falling)	2.625	2.559	2.691	2.573	2.678	V
Z (falling)	2.313	2.255	2.371	2.267	2.359	V
Y (falling)	2.188	2.133	2.243	2.144	2.232	V
W (falling)	1.665	1.623	1.707	1.632	1.698	V
V (falling)	1.575	1.536	1.614	1.544	1.607	V

Table 7.V_{CC} voltage thresholds



5 Package mechanical data

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK[®] packages, depending on their level of environmental compliance. ECOPACK[®] specifications, grade definitions and product status are available at: *www.st.com*. ECOPACK[®] is an ST trademark.





Figure 15. TDFN – 8-lead 2 x 2 x 0.75 mm, 0.5 mm pitch package outline

Table 8.	TDFN – 8-lead 2 x 2 x 0.75 mm, 0.5 mm pitch package mechanical data

Symbol	D	imension (mn	n)	Dimension (inches)			
	Min.	Nom.	Max.	Min.	Nom.	Max.	
А	0.70	0.75	0.80	0.028	0.030	0.031	
A1	0.00	0.02	0.05	0.000	0.001	0.002	
b	0.15	0.20	0.25	0.006	0.008	0.010	
D BSC	1.9	2.00	2.1	0.075	0.079	0.083	
E BSC	1.9	2.00	2.1	0.075	0.079	0.083	
е		0.50			0.020		
L	0.45	0.55	0.65	0.018	0.022	0.026	





Figure 16. Landing pattern - TDFN – 8-lead 2 x 2 mm without thermal pad

Parameter	Description	Dimension (mm)					
Farameter	Description	Min.	Nom.	Max.			
L	Contact length	1.05		1.15			
b	Contact width	0.25		0.30			
E	Max. land pattern Y-direction	_	2.85	—			
E1	Contact gap spacing	—	0.65	—			
D	Max. land pattern X-direction	_	1.75	—			
Р	Contact pitch		0.5	_			

Figure 17. Carrier tape



 Table 10.
 Carrier tape dimensions

Package	w	D	Е	P ₀	P ₂	F	A ₀	B ₀	K ₀	P ₁	т	Unit	Bulk qty.
TDFN8	8.00 +0.30 -0.10	1.50 +0.10/ -0.00	1.75 ±0.10		2.00 ±0.10	3.50 ±0.05	2.30 ±0.05	2.30 ±0.05	1.00 ±0.05	4.00 ±0.10	0.250 ±0.05	mm	3000





Figure 18. Reel dimensions

Table 11	. Reel	dimensions

Tape sizes	A max.	B min.	С	D min.	N min.	G	T max.
8 mm	180 (7 inches)	1.50	13.0 +/- 0.20	20.20	60	8.4 +2/-0	14.40











Note: 1 Drawings are not to scale.

2 All dimensions are in mm, unless otherwise noted.



6 Part numbering

Table 12. Ordering int	formation schem	е						
Example:	STM6505	w	С	Α	в	DG	6	F
Device type								
STM6502 ⁽¹⁾								
STM6503								
STM6504 ⁽¹⁾								
STM6505								
Reset (V _{CC} monitoring) th (V _{RST}), typ., falling	reshold voltage							
L = 4.625 V								
S = 2.925 V								
R = 2.625 V								
Z = 2.313 V								
W = 1.665 V								
V = 1.575 V								
Smart Reset setup delay (pull-up on all Smart Rese			nput					
A = user-programmable (ex	ternal capacitor); no	input pull-	up					
C = user-programmable (ex	ternal capacitor); 65	5 kΩ input p	oull-up					
E = 2 or 6 or 10 s min., use	r-programmable (thr	ee-state); r	no input pull-	up				
F = 2 or 6 or 10 s min., user	r-programmable (thre	ee-state); 6	$65 \ k\Omega$ input p	ull-up				
Output type								
A = open-drain, no pull-up,	active-low							
Reset timeout period (t _{RE}	c)							
A = 140 ms min.								
B = 240 ms min.								
Package								
DG = TDFN8 2 x 2 x 0.75 n	nm, 0.5 mm pitch							
Temperature range								
6 = -40 °C to +85 °C								
Shipping method								
F = ECOPACK [®] package, ta	ape and reel							

1. Contact local ST sales office for availability.

For device options currently available refer to *Table 13*. For other options, voltage threshold values etc. or for more information on any aspect of this device, please contact the ST sales office nearest you.



7 Package marking

Table 13. Package marking

Part number	t _{SRC} delay control	Smart Reset inputs ⁽¹⁾	V _{RST}	RST output ⁽¹⁾	t _{REC} option	BLD output ⁽¹⁾	Topmark
STM6503VEAADG6F	TSR	AL	V	AL, OD	А	—	3VG
STM6504SEABDG6F ⁽²⁾	TSR	AL	S	AL, OD	В	_	4SG
STM6505SCABDG6F	C _{SRC}	AL, PU	S	AL, OD	В	AL, OD	5SK
STM6505RCABDG6F	C _{SRC}	AL, PU	R	AL, OD	В	AL, OD	5RK
STM6505WCABDG6F	C _{SRC}	AL, PU	W	AL, OD	В	AL, OD	5WK

1. AL = active-low, AH = active-high, PU = with internal pull-up resistor, OD = open-drain.

2. Contact local ST sales office for availability.



8 Revision history

Date	Revision	Changes
31-Aug-2009	1	Initial release.
06-Nov-2009	2	Updated <i>Applications</i> , <i>Section 1</i> , <i>Section , Figure 3</i> to <i>Figure 6</i> updated and moved to <i>Section</i> , updated <i>Table 1</i> , <i>Table 2</i> , <i>Table 3</i> , <i>Table 4</i> , <i>Table 6</i> , <i>Table 12</i> , <i>Section 1.2.3</i> , <i>Section 1.2.7</i> , <i>Section 1.2.9</i> , <i>Section 5</i> , added package footprint, tape and reel information, and <i>Section 7</i> .
15-Jan-2010	3	Updated <i>Features</i> , <i>Section 1</i> , <i>Section 1.2.6</i> , <i>Table 1</i> , <i>Table 2</i> , <i>Figure 5</i> , <i>Figure 6</i> , <i>Table 3</i> , <i>Table 6</i> , <i>Table 12</i> , <i>Table 13</i> , removed Table 4.
01-Mar-2010	4	Updated title of datasheet, <i>Features, Applications, Table 1, 2, 6, 12,</i> footnote 5 of <i>Table 6</i> ; updated <i>Figure 3, 4</i> ; added <i>Section 2: Typical operating characteristics</i> ; minor textual and formatting changes.
21-Jun-2010	5	Updated <i>Features</i> , <i>Section 1</i> , <i>Figure 8</i> , footnote 1 and 2 of <i>Table 3</i> , updated <i>Table 4</i> , added footnote 2 to <i>Table 4</i> , <i>Table 6</i> , added footnote 6 to <i>Table 6</i> , updated <i>Table 6</i> to <i>Table 9</i> , and added footnote 2 of <i>Table 13</i> .

Table 14.	Document revision history
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